

10th International Conference on Radiation Effects on Semiconductor Materials, Detectors and Devices

Wednesday, 8 October 2014

Materials and Defects Characterisation (14:30 - 15:50)

time	[id] title	presenter
14:30	[46] Electronic stimulation of interstitial defect reactions in irradiated p-type silicon	MAKARENKO, Leonid
14:50	[34] On polarization in compensated semiconductors	RUZIN, Arie
15:10	[35] Processing and characterization of epitaxial grown GaAs radiation detectors	PELTOLA, Timo Hannu Tapani
15:30	[47] An evidence of strong electron-phonon interaction in the neutron irradiation induced defects in silicon	RUMBAUSKAS, Vytautas